600V 10A N-Channel Enhancement Mode Power MOSFET

General Description

BXP10N60 is Bridgelux high voltage MOSFET family based on advanced planar DMOS technology. This advanced MOSFET family has optimized on-state resistance, and also provides superior switching performance and higher avalanche energy strength. This device family is suitable for high efficiency switch mode power supplies.

SYMBOL







TO-220F

TO-220

ASSEMBLY MESSAGE

Product Name	Package	Packaging
BXP10N60P	TO-220	Tube
BXP10N60F	TO-220F	Tube

ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Parameter		<u>Cumb al</u>	Rati	11	
		Symbol –	BXP10N60P	BXP10N60F	– Unit
Drain-Source Voltage		V _{DSS}	60	V	
Drain Current	Continuous (T _c = 25°C)	1	10	Α	
Drain Current	Continuous (T _c = 100°C)		5		Α
Drain Current	Pulsed (Note1)	I _{DM}	40		Α
Gate-Source Voltage		V _{GSS}	±30		V
	Single Pulse (Note2)	E _{AS}	725		mJ
Avalanche Energy	Repetitive (Note1)	E _{AR}	16.5		mJ
Avalanche Current (Note1)		I _{AR}	10		Α
Peak Diode Recovery dv/dt (Note3)		dv/dt	4.5		V/ns
Power Dissipation (Note	T _C =25°C	D D	178	48	W
2) Derate above 2		- P _D -	1.42	0.38	W/°C
Maximum Junction Temperature		TJ	150		°C
Storage Temperature Range		T _{STG}	-55 to 150		°C

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. L=14.5mH, I_{AS}=10.0A, V_{DD}=50V, RG=25 $\Omega,$ Starting TJ = 25°C

3. I_{SD} ≤ 7.0A, di/dt ≤ 300A/µs, V_{DD} ≤ BV_{DSS}, Starting TJ = 25°C

- RDSON \leqslant 0.9 Ω @Vgs=10V, Id=5A
- Excellent RDS(ON) and Low Gate Charge
- Fast switching capability
- Lead free product is acquired



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BXP10N60

THERMAL CHARACTERISTICS

Deremeter	Symbol	Ma	llait	
Parameter	Symbol	BXP10N60P	BXP10N60F	Unit
Thermal Resistance, Junction-to-Case	R _{θJC}	0.7	2.6	°C / W
Thermal Resistance, Junction-to-Ambient	R _{0JA}	62.5	122	°C / W

ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS	I			1	1	1
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250µA	600			V
	I _{DSS}	VDS=600V, VGS=0V			1	uA
Zero Gate Voltage Drain Current		VDS=480V, TC = 125°C			100	uA
Gate-Body Leakage Current, Forward		VGS=30V			100	nA
Gate-Body Leakage Current, Reverse	- I _{GSS}	VGS=-30V			-100	nA
Breakdown Voltage Temperature	∆BVDSS/			0.00		N//*O
Coefficient	∆TJ	ID = 250 μA		0.68		V/℃
ON CHARACTERISTICS			-			
Gate Threshold Voltage	V _{GS(TH)}	VDS=VGS, ID=250µA	2		4	V
Drain-Source On-State Resistance	RDS(ON)	VGS=10V, ID=5A		0.68	0.9	Ω
Forward Transconductance (Note4)	g⊧s	VDS = 50V, ID = 5A		8.2		S
DYNAMIC PARAMETERS	-	1	1	1	1	
Input Capacitance	C _{ISS}			1302		pF
Output Capacitance	Coss	VDS=25V, VGS=0V,		135		pF
Reverse Transfer Capacitance	Crss	- f=1.0MHz -		19		pF
SWITCHING PARAMETERS		1		1	1	1
Turn-ON Delay Time	t _{D(ON)}			62		ns
Turn-ON Rise Time	t _R	VDD=300V, ID=10A, VGS		102		ns
Turn-OFF Delay Time	t _{D(OFF)}	= 10V ,RG=10Ω		200		ns
Turn-OFF Fall-Time	t⊨	- (Note4,5)		78		ns
Total Gate Charge(Note5)	Q _G	VDS =480V, VGS =10V, ID		32		nC
Gate Source Charge	Q _{GS}	=10A		6.2		nC
Gate Drain Charge	Q _{GD}	(Note4,5)		11		nC
SOURCE- DRAIN DIODE RATINGS		ACTERISTICS			I	
Drain-Source Diode Forward Voltage	V _{SD}	IS=10A, VGS=0V			1.4	V
Diode Continuous Forward Current	Is				10	Α
Pulsed Drain-Source Current	I _{SM}				40	Α
Reverse Recovery Time	t _{RR}	VGS = 0 V, ISD = 10A		450		ns
Reverse Recovery Charge	Q _{RR}	di/dt=100 A/µs (Note4,5)		4.46		uC

Note: 4. Pulse Test : Pulse width \leq 300µs, Duty cycle \leq 2%

5. Essentially independent of operating temperature

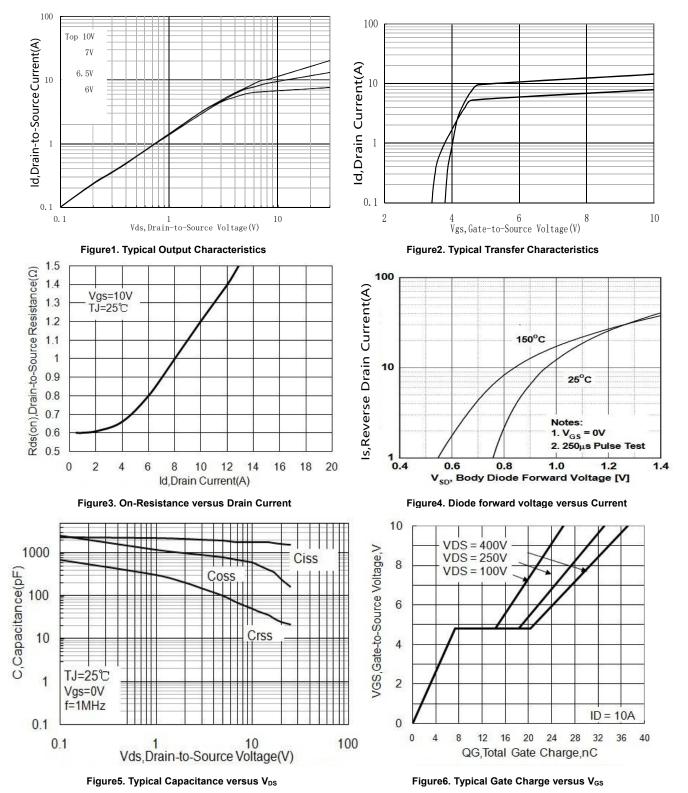


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Halogen Free

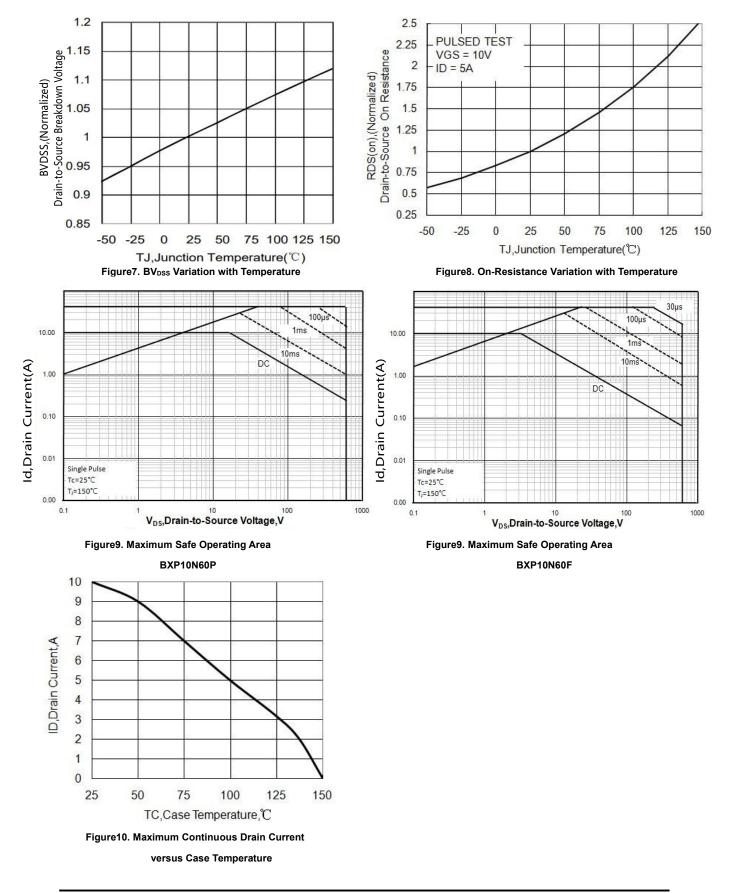
BXP10N60

TYPICAL CHARACTERISTICS





TYPICAL CHARACTERISTICS(Cont.)

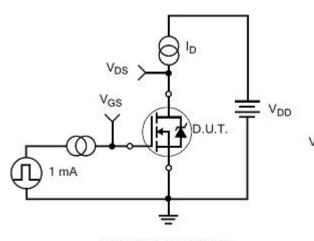




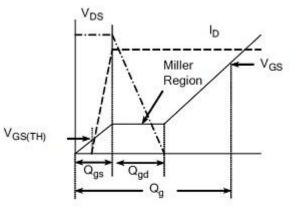
BXP10N60



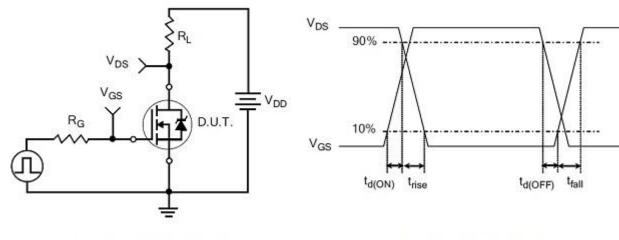
TEST CIRCUITS AND WAVEFORMS



Gate Charge Test Circuit



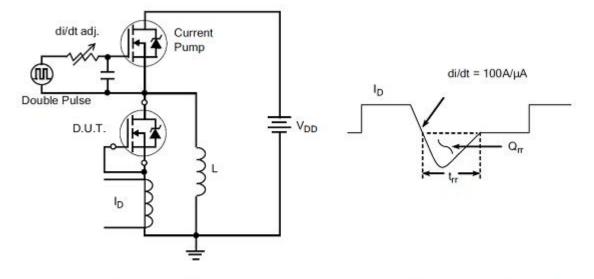
Gate Charge Waveform



Resistive Switching Test Circuit

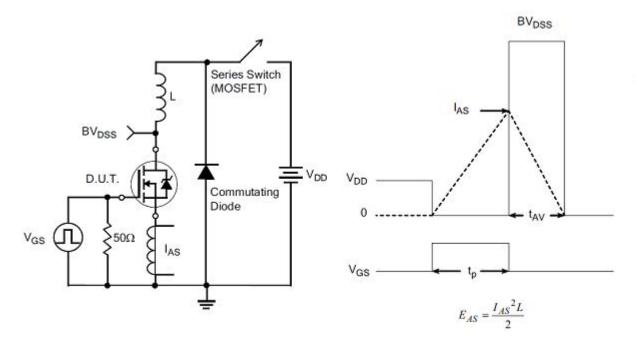
Resistive Switching Waveforms

TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms



Revision history

Document revision history

Date	Revision	Changes
5-Sep-2021	1.0	First release
7-Jan-2022	1.1	Update parameter

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